

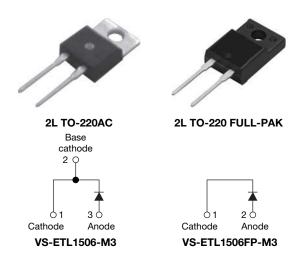
Vishay Semiconductors

COMPLIANT

HALOGEN

FREE

## Ultrafast Rectifier, 15 A FRED Pt®



PRODUCT SUMMARY					
Package	2L TO-220AC, 2L TO-220FP				
I <sub>F(AV)</sub>	15 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	1.1 V				
t <sub>rr</sub> (typ.)	60 ns				
T <sub>J</sub> max.	175 °C				
Diode variation	Single die				

#### **FEATURES**

- · State of the art low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- True 2 pin package
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified according to JEDEC-JESD47

#### **DESCRIPTION**

State of the art, ultralow  $V_F$ , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

#### **APPLICATIONS**

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	$V_{RRM}$		600	V		
Assessment in DO	I <sub>F(AV)</sub>	T <sub>C</sub> = 157 °C	15	А		
Average rectified forward current in DC FULL-PAK		T <sub>C</sub> = 120 °C	15			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	200			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 15 A	-	0.99	1.07	V	
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	0.85	0.91		
Deverage legitage everyont		$V_R = V_R$ rated	-	0.01	15		
Reverse leakage current I <sub>R</sub>		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	6	100	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	12	=	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH	

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# VS-ETL1506-M3, VS-ETL1506FP-M3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 A, dI_F/dt = 10$	$I_F = 1 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s, } V_R = 30 \text{ V}$		60	110	
Reverse recovery time		$I_F = 15 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	185	270	
neverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	210	-	ns
		T <sub>J</sub> = 125 °C		-	290	-	
Dook room ourrent		T <sub>J</sub> = 25 °C	$I_F = 15 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	20	-	Α
Peak recovery current I <sub>RRM</sub>	IRRM	T <sub>J</sub> = 125 °C		-	26	-	A
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	2.2	-	μC
		T <sub>J</sub> = 125 °C		-	4.0	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C	
Thermal resistance,	D		-	1.2	1.4		
junction to case FULL-PAK	$R_{thJC}$		-	3.7	4.3		
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-		
Maight			-	2	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6	_	12	kgf · cm	
Woulding torque			(5)		(10)	(lbf·in)	
Marking device		Case style 2L TO-220AC	AC ETL1506		1506		
ivial Killig Gevice		Case style 2L TO-220 FULL-PAK		ETL1	506FP		



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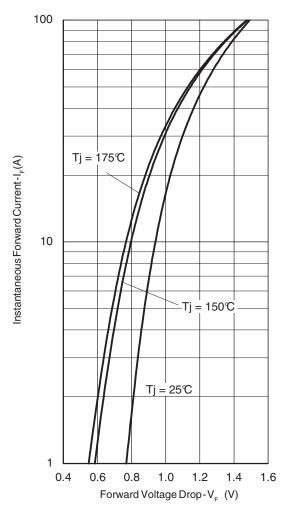


Fig. 1 - Typical Forward Voltage Drop Characteristics

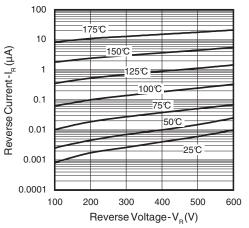


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

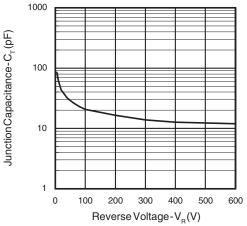


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

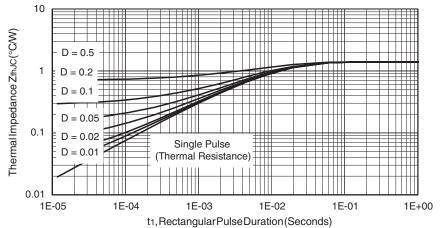


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

#### Vishay Semiconductors Ultrafast Rectifier, 15 A FRED Pt®



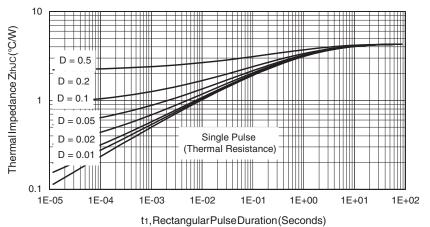


Fig. 5 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (FULL-PAK)

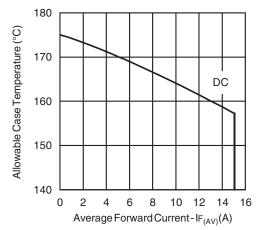


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

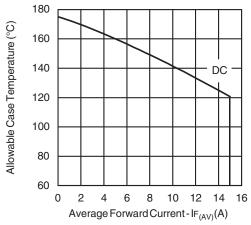


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

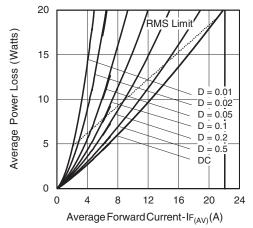


Fig. 8 - Forward Power Loss Characteristics





## Ultrafast Rectifier, 15 A FRED Pt® Vishay Semiconductors

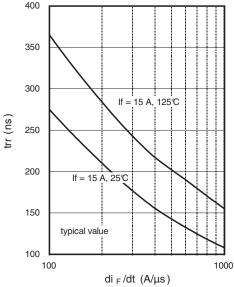


Fig. 9 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

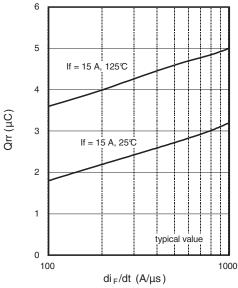


Fig. 10 - Typical Stored Charge vs. dl<sub>F</sub>/dt

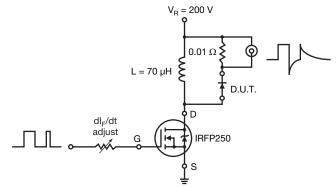
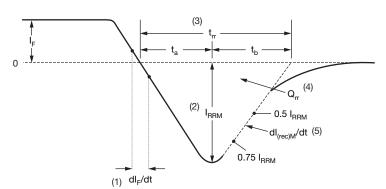


Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$ 
  - $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (5)  $dl_{(rec)M}/dt$  peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 12 - Reverse Recovery Waveform and Definitions

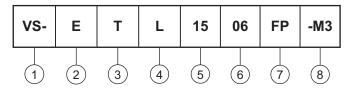
## VS-ETL1506-M3, VS-ETL1506FP-M3

Vishay Semiconductors Ultrafast Rectifier, 15 A FRED Pt®



#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = Single diode

**3** - T = TO-220

4 - L = Hyperfast recovery time

5 - Current code: 15 = 15 A

Voltage code: 06 = 600 V

**7** - • None = TO-220

• FP = FULL-PAK

8 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-ETL1506-M3	50	1000	Antistatic plastic tube			
VS-ETL1506FP-M3	50	1000	Antistatic plastic tube			

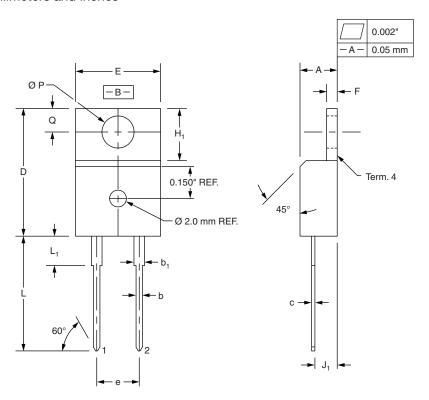
LINKS TO RELATED DOCUMENTS					
Dimensions	2L TO-220AC	www.vishay.com/doc?95259			
Differisions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260			
Part marking information	2L TO-220AC	www.vishay.com/doc?95391			
Part marking information	2L TO-220 FULL-PAK	www.vishay.com/doc?95392			



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## True 2 Pin TO-220

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	METERS	INC	HES
STMBOL	MIN.	MAX.	MIN.	MAX.
А	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
Е	10.04	10.41	0.395	0.410
е	5.08	BSC	0.200 BSC	
F	1.22	1.37	0.048	0.054
H <sub>1</sub>	5.97	6.47	0.235	0.255
J <sub>1</sub>	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L <sub>1</sub> <sup>(1)</sup>	3.31	3.81	0.130	0.150
Ø P	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

#### Notes

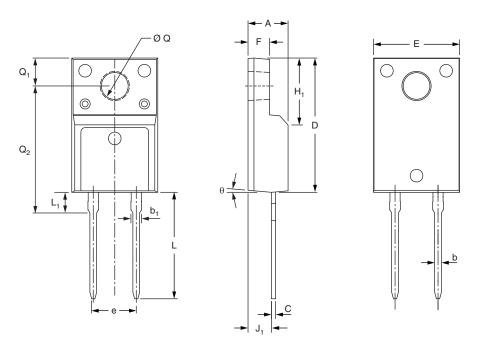
- $^{(1)}$  Lead dimension and finish uncontrolled in  $L_1$
- These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87
- Controling dimension: Inch



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## True 2 Pin TO-220 FULL-PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLI	METERS	INC	HES
STMBOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
е	5.08	typical	0.200	typical
F	2.34	2.74	0.092	0.107
H <sub>1</sub>	6.50	6.90	0.256	0.272
J <sub>1</sub>	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L <sub>1</sub>	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q <sub>1</sub>	3.10	3.50	0.122	0.138
$Q_2$	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°



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